

## Description

The 9FGV1004C/9FGV1008C are members of Renesas' PhiClock™ programmable clock generator family. The 9FGV1004 provides 1 copy each of 2 integer-related frequencies, 2 copies of a fractional or spread-spectrum frequency. The 9FGV1008 provides 1 integer frequency and 1 copy of a fractional or spread-spectrum frequency. Four user-defined configurations may be selected via two hardware select pins or two I<sup>2</sup>C bits, allowing easy software selection of the desired configuration. Any one of the four OTP configurations may be specified as the default when operating in I<sup>2</sup>C mode. Four unique I<sup>2</sup>C addresses are available, allowing easy I<sup>2</sup>C access to multiple components.

## Typical Applications

- High-performance Computing (HPC)
- eSSDs
- 10G/25G/100G Ethernet
- Fiber Optic Modules
- Data Center Accelerators

## Output Features

- 9FGV1004: 4 programmable output pairs plus 2 LVCMOS REF outputs
- 9FGV1008: 2 programmable output pairs plus 1 LVCMOS REF output
- 2 integer and 1 fractional/spread spectrum output frequency per configuration
- 1MHz–325MHz LVDS or LP-HCSL outputs
- 1MHz–200MHz LVCMOS outputs
- 1MHz–156.25MHz spread spectrum or fractional output

## PCIe Clocking Architectures

- Common Clocked (CC)
- Independent Reference without spread spectrum (SRnS)
- See [AN1001](#) for Independent Reference with spread-spectrum (SRIS) applications

## Features

- 1.8V, 2.5V or 3.3V power supplies
- Individual V<sub>DDO</sub> for each programmable output pair
- Supports HCSL, LVDS and LVCMOS I/O standards
- Low-Power HCSL technology for improved performance, lower power and higher integration:
  - Programmable output impedance of 85Ω or 100Ω
- Supports LVPECL and CML logic with easy AC coupling – see [AN-891](#) for alternate terminations
- On-board OTP supports up to 4 complete configurations selectable via strapping pins or I<sup>2</sup>C
- Internal crystal load capacitors
- Programmable spread-spectrum modulation frequency and amount
- < 150mW at 1.8V with LP-HCSL outputs at 100MHz (9FGV1004)
- < 135mW at 1.8V with LP-HCSL outputs at 100MHz (9FGV1008)
- 4 programmable I<sup>2</sup>C addresses: D0, D2, D4, D6
- Easily configured with Renesas [Timing Commander™](#) software or Web Configurator
- Space saving 4 × 4 mm 24-VFQFPN, 24-LGA (9FGV1004) and 3 × 3 mm 16-LGA (9FGV1008) packages
- Integrated crystal option (9FGV1004CQ, 9FGV1008CQ)

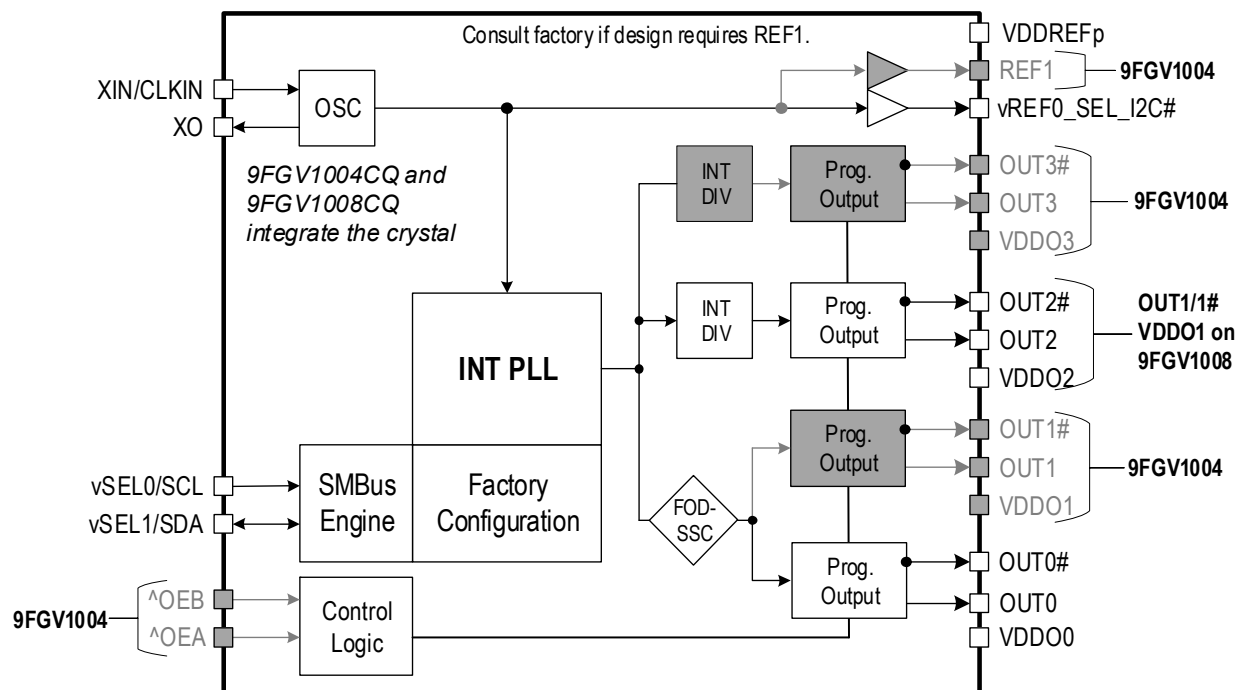
## Key Specifications

- 12kHz–20MHz typical phase jitter at 156.25M Hz (SSC off or on) 224fs RMS (9FGV1008 OUT1)
- 12kHz–20MHz typical phase jitter at 156.25MHz (SSC off or on) 267fs RMS (9FGV1004 OUT3)
- PCIe Gen1–4 compliant (spread spectrum off)
- PCIe Gen1–3 compliant (spread spectrum on)
- See [AN1001](#) for generating PCIe Gen5 clocks from the 9FGV1004C/9FGV1008C

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# Block Diagram

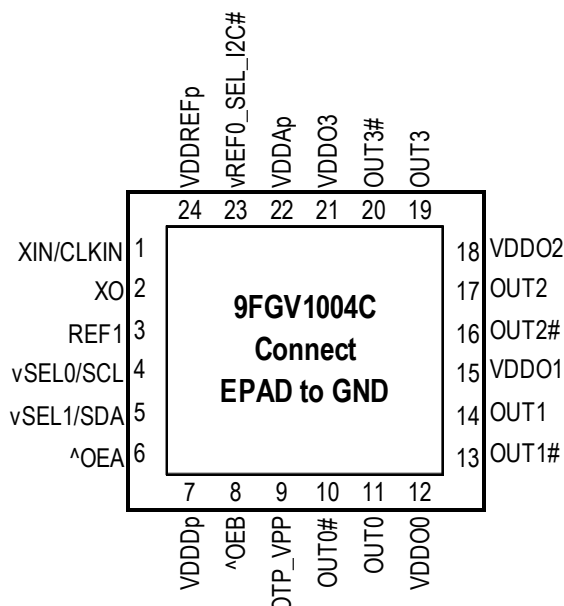


**Table 1. OE Mapping**

| OE[B:A] | OUT0    | OUT1    | OUT2    | OUT3    | REF0    | REF1    |
|---------|---------|---------|---------|---------|---------|---------|
| 00      | Running | Stopped | Running | Stopped | Running | Running |
| 01      | Running | Running | Stopped | Stopped | Running | Running |
| 10      | Stopped | Stopped | Running | Running | Running | Running |
| 11      | Running | Running | Running | Running | Running | Running |

# Pin Assignments

**Figure 1. Pin Assignments for 4 x 4 mm 24-VFQFPN Package – Top View**



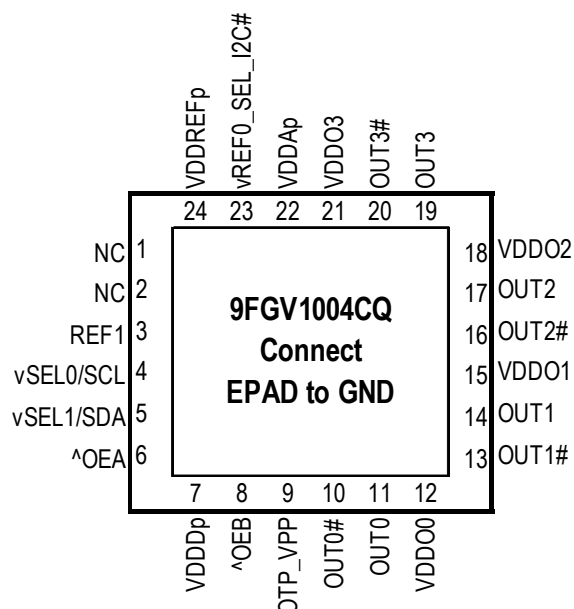
**4 x 4 mm 24-VFQFPN, 0.5mm pitch**

^ prefix indicates internal pull-up

v prefix indicates internal pull-down resistor

Note: The order of OUT3 is reversed from OUT[0:2]

**Figure 2. Pin Assignments for 4 x 4 mm 24-LGA Package – Top View**



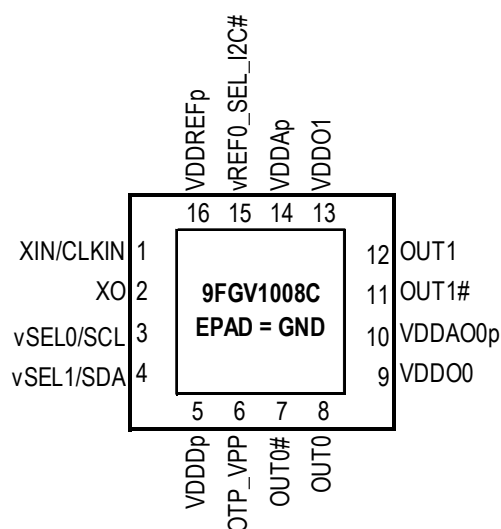
**4 x 4 mm 24-LGA, 0.5mm pitch**

^ prefix indicates internal pull-up resistor

v prefix indicates internal pull-down resistor

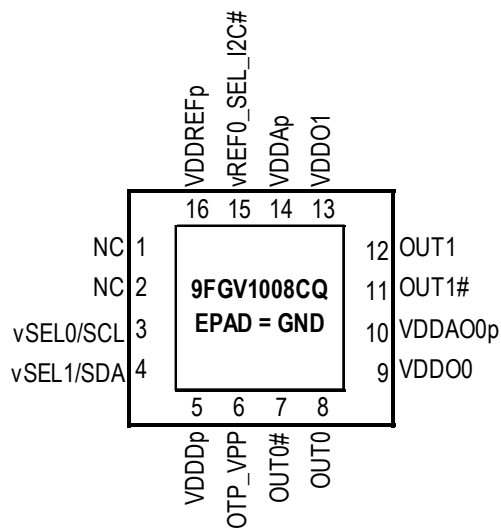
Note: The order of OUT3 is reversed from OUT[0:2]

**Figure 3. Pin Assignments for 3 x 3 mm 16-LGA Package – Top View**



**3 x 3 mm 16-LGA , 0.5mm pitch**

^ prefix indicates internal pull-up  
 v prefix indicates internal pull-down



**3 x 3 mm 16-LGA , 0.5mm pitch**

^ prefix indicates internal pull-up  
 v prefix indicates internal pull-down

# Pin Descriptions

**Table 2. 9FGV1004 Pin Descriptions**

| Number           | Name           | Type        | Description                                                                                                                                                                                                                                                      |
|------------------|----------------|-------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 1 <sup>[a]</sup> | XIN/CLKIN      | Input       | Crystal input or reference clock input.                                                                                                                                                                                                                          |
| 2 <sup>a]</sup>  | XO             | Output      | Crystal output.                                                                                                                                                                                                                                                  |
| 3                | REF1           | Output      | LVC MOS reference output.                                                                                                                                                                                                                                        |
| 4                | vSEL0/SCL      | Input       | Select pin for internal frequency configurations/I <sup>2</sup> C clock pin. Function is determined by state of SEL_I2C# upon power-up. This pin has an internal pull-down.                                                                                      |
| 5                | vSEL1/SDA      | I/O         | Select pin for internal frequency configurations/I <sup>2</sup> C data pin. Function is determined by state of SEL_I2C# upon power-up. This pin has an internal pull-down.                                                                                       |
| 6                | ^OEA           | Input       | Active high input for enabling outputs. This pin has an internal pull-up resistor.<br>0 = disable outputs, 1 = enable outputs.                                                                                                                                   |
| 7                | VDDDp          | Power       | Digital power. Connect to 1.8V, 2.5V or 3.3V.                                                                                                                                                                                                                    |
| 8                | ^OEB           | Input       | Active high input for enabling outputs. This pin has an internal pull-up resistor.<br>0 = disable outputs, 1 = enable outputs.                                                                                                                                   |
| 9                | OTP_VPP        | Power       | Voltage for programming OTP. During normal operation, this pin should be connected to the same power rail as V <sub>DD</sub> .                                                                                                                                   |
| 10               | OUT0#          | Output      | Complementary output clock 0.                                                                                                                                                                                                                                    |
| 11               | OUT0           | Output      | Output clock 0.                                                                                                                                                                                                                                                  |
| 12               | VDDO0          | Power       | Power supply for output 0.                                                                                                                                                                                                                                       |
| 13               | OUT1#          | Output      | Complementary output clock 1.                                                                                                                                                                                                                                    |
| 14               | OUT1           | Output      | Output clock 1.                                                                                                                                                                                                                                                  |
| 15               | VDDO1          | Power       | Power supply for output 1.                                                                                                                                                                                                                                       |
| 16               | OUT2#          | Output      | Complementary output clock 2.                                                                                                                                                                                                                                    |
| 17               | OUT2           | Output      | Output clock 2.                                                                                                                                                                                                                                                  |
| 18               | VDDO2          | Power       | Power supply for output 2.                                                                                                                                                                                                                                       |
| 19               | OUT3           | Output      | Output clock 3.                                                                                                                                                                                                                                                  |
| 20               | OUT3#          | Output      | Complementary output clock 3.                                                                                                                                                                                                                                    |
| 21               | VDDO3          | Power       | Power supply for output 3.                                                                                                                                                                                                                                       |
| 22               | VDDAp          | Power       | Analog power. Connect to same voltage as VDDDp, with proper filtering.                                                                                                                                                                                           |
| 23               | vREF0_SEL_I2C# | Latched I/O | Latched input/LVC MOS output. At power-up, the state of this pin is latched to select the state of the I <sup>2</sup> C pins. After power-up, the pin acts as an LVC MOS reference output. This pin has an internal pull-down.<br>1 = SEL0/SEL1.<br>0 = SCL/SDA. |
| 24               | VDDREFp        | Power       | Power supply for REF0 and REF1 and the internal XO. Programmable to 1.8V, 2.5V or 3.3V.                                                                                                                                                                          |
| 25               | EPAD           | GND         | Connect to ground.                                                                                                                                                                                                                                               |

**Note:** Unused outputs can be programmed off and left floating. V<sub>DDREF</sub> and V<sub>DDO0</sub> have to be connected.

[a] These pins are 'No Connect' on 9FGV100xQ integrated quartz versions and should have no stubs.

**Table 3. 9FGV1008 Pin Descriptions**

| Number           | Name           | Type        | Description                                                                                                                                                                                                                                                   |
|------------------|----------------|-------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 1 <sup>[a]</sup> | XIN/CLKIN      | Input       | Crystal input or reference clock input.                                                                                                                                                                                                                       |
| 2 <sup>[a]</sup> | XO             | Output      | Crystal output.                                                                                                                                                                                                                                               |
| 3                | vSEL0/SCL      | Input       | Select pin for internal frequency configurations/I <sup>2</sup> C clock pin. Function is determined by state of SEL_I2C# upon power up. This pin has an internal pull-down.                                                                                   |
| 4                | vSEL1/SDA      | I/O         | Select pin for internal frequency configurations/I <sup>2</sup> C data pin. Function is determined by state of SEL_I2C# upon power-up. This pin has an internal pull-down.                                                                                    |
| 5                | VDDDp          | Power       | Digital power. Connect to 1.8V, 2.5V or 3.3V.                                                                                                                                                                                                                 |
| 6                | OTP_VPP        | Power       | Voltage for programming OTP. During normal operation, this pin should be connected to the same power rail as VDDD.                                                                                                                                            |
| 7                | OUT0#          | Output      | Complementary output clock 0.                                                                                                                                                                                                                                 |
| 8                | OUT0           | Output      | Output clock 0.                                                                                                                                                                                                                                               |
| 9                | VDDO0          | Power       | Power supply for output 0.                                                                                                                                                                                                                                    |
| 10               | VDDAO0p        | Power       | Analog power supply for output 0. This pin should be connected to the same power rail as output 0 and filtered appropriately. Nominal voltages are 1.8V, 2.5V or 3.3V.                                                                                        |
| 11               | OUT1#          | Output      | Complementary output clock 1.                                                                                                                                                                                                                                 |
| 12               | OUT1           | Output      | Output clock 1.                                                                                                                                                                                                                                               |
| 13               | VDDO1          | Power       | Power supply for output 1.                                                                                                                                                                                                                                    |
| 14               | VDDAp          | Power       | Analog power. Connect to same voltage as VDDDp, with proper filtering.                                                                                                                                                                                        |
| 15               | vREF0_SEL_I2C# | Latched I/O | Latched input/LVCMOS Output. At power-up, the state of this pin is latched to select the state of the I <sup>2</sup> C pins. After power-up, the pin acts as a LVCMOS reference output. This pin has an internal pull-down.<br>1 = SEL0/SEL1.<br>0 = SCL/SDA. |
| 16               | VDDREFp        | Power       | Power supply for REF outputs and the internal XO. Nominal voltages are 1.8V, 2.5V or 3.3V.                                                                                                                                                                    |
| 17               | EPAD           | GND         | Connect to ground.                                                                                                                                                                                                                                            |

**Note:** Unused outputs can be programmed off and left floating. V<sub>DDREF</sub> and V<sub>DDO0</sub> have to be connected.

[a] These pins are 'No Connect' on 9FGV100xQ integrated quartz versions and should have no stubs.

## Absolute Maximum Ratings

The absolute maximum ratings are stress ratings only. Stresses greater than those listed below can cause permanent damage to the device. Functional operation of the 9FGV1004C/9FGV1008C at absolute maximum ratings is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

**Table 4. Absolute Maximum Ratings**

| Parameter                                         | Rating                    |
|---------------------------------------------------|---------------------------|
| Supply Voltage, $V_{DDA}$ , $V_{DDD}$ , $V_{DDO}$ | 3.9V                      |
| Storage Temperature, $T_{STG}$                    | -65°C to 150°C            |
| ESD Human Body Model                              | 2000V                     |
| Junction Temperature                              | 125°C                     |
| <b>Inputs</b>                                     |                           |
| XIN/CLKIN                                         | 0V to 1.2V voltage swing  |
| Other Inputs                                      | -0.5V to $V_{DDD}$        |
| <b>Outputs</b>                                    |                           |
| Outputs, $V_{DDO}$ (LVCMOS)                       | -0.5V to $V_{DDO} + 0.5V$ |
| Outputs, IO (SDA)                                 | 10mA                      |

## Thermal Characteristics

**Table 5. Thermal Characteristics—24-pin Devices**

| Parameter                                                      | Symbol         | Conditions                      | Package | Typical Values | Unit | Notes |
|----------------------------------------------------------------|----------------|---------------------------------|---------|----------------|------|-------|
| Thermal Resistance<br>(devices with external crystal)          | $\theta_{JC}$  | Junction to case                | NBG24   | 52             | °C/W | 1     |
|                                                                | $\theta_{Jb}$  | Junction to base                |         | 2.3            | °C/W | 1     |
|                                                                | $\theta_{JA0}$ | Junction to air, still air      |         | 44             | °C/W | 1     |
|                                                                | $\theta_{JA1}$ | Junction to air, 1 m/s air flow |         | 37             | °C/W | 1     |
|                                                                | $\theta_{JA3}$ | Junction to air, 3 m/s air flow |         | 33             | °C/W | 1     |
|                                                                | $\theta_{JA5}$ | Junction to air, 5 m/s air flow |         | 32             | °C/W | 1     |
| Thermal Resistance Q-series<br>(devices with internal crystal) | $\theta_{JC}$  | Junction to case                | LTG24   | 57.3           | °C/W | 1     |
|                                                                | $\theta_{Jb}$  | Junction to base                |         | 24.3           | °C/W | 1     |
|                                                                | $\theta_{JA0}$ | Junction to air, still air      |         | 79.8           | °C/W | 1     |
|                                                                | $\theta_{JA1}$ | Junction to air, 1 m/s air flow |         | 73.9           | °C/W | 1     |
|                                                                | $\theta_{JA3}$ | Junction to air, 3 m/s air flow |         | 69.9           | °C/W | 1     |
|                                                                | $\theta_{JA5}$ | Junction to air, 5 m/s air flow |         | 67.3           | °C/W | 1     |

<sup>1</sup> EPAD soldered to board.



**Table 6. Thermal Characteristics—16-pin Devices**

| Parameter                                                      | Symbol         | Conditions                      | Package | Typical Values | Unit | Notes |
|----------------------------------------------------------------|----------------|---------------------------------|---------|----------------|------|-------|
| Thermal Resistance<br>(devices with external crystal)          | $\theta_{JC}$  | Junction to case                | LTG16   | 66             | °C/W | 1     |
|                                                                | $\theta_{Jb}$  | Junction to base                |         | 5.1            | °C/W | 1     |
|                                                                | $\theta_{JA0}$ | Junction to air, still air      |         | 63             | °C/W | 1     |
|                                                                | $\theta_{JA1}$ | Junction to air, 1 m/s air flow |         | 56             | °C/W | 1     |
|                                                                | $\theta_{JA3}$ | Junction to air, 3 m/s air flow |         | 51             | °C/W | 1     |
|                                                                | $\theta_{JA5}$ | Junction to air, 5 m/s air flow |         | 49             | °C/W | 1     |
| Thermal Resistance Q-series<br>(devices with internal crystal) | $\theta_{JC}$  | Junction to case                | LTG16   | 82.1           | °C/W | 1     |
|                                                                | $\theta_{Jb}$  | Junction to base                |         | 42.3           | °C/W | 1     |
|                                                                | $\theta_{JA0}$ | Junction to air, still air      |         | 93.6           | °C/W | 1     |
|                                                                | $\theta_{JA1}$ | Junction to air, 1 m/s air flow |         | 87.1           | °C/W | 1     |
|                                                                | $\theta_{JA3}$ | Junction to air, 3 m/s air flow |         | 83.3           | °C/W | 1     |
|                                                                | $\theta_{JA5}$ | Junction to air, 5 m/s air flow |         | 66             | °C/W | 1     |

<sup>1</sup> EPAD soldered to board.

## Recommended Operating Conditions

**Table 7. Recommended Operating Conditions**

| Symbol     | Parameter                                                                                           | Minimum | Typical | Maximum | Unit |
|------------|-----------------------------------------------------------------------------------------------------|---------|---------|---------|------|
| $V_{DDOx}$ | Power supply voltage for supporting 1.8V outputs.                                                   | 1.71    | 1.8     | 1.89    | V    |
|            | Power supply voltage for supporting 2.5V outputs.                                                   | 2.375   | 2.5     | 2.625   | V    |
|            | Power supply voltage for supporting 3.3V outputs.                                                   | 3.135   | 3.3     | 3.465   | V    |
| $V_{DDD}$  | Power supply voltage for core logic functions.                                                      | 1.71    | -       | 3.465   | V    |
| $V_{DDA}$  | Analog power supply voltage. Use filtered analog power supply if available.                         | 1.71    | -       | 3.465   | V    |
| $T_A$      | Operating temperature, ambient.                                                                     | -40     | -       | 85      | °C   |
| $C_L$      | Maximum load capacitance (3.3V LVCMOS only).                                                        | -       | -       | 15      | pF   |
| $t_{PU}$   | Power up time for all $V_{DDs}$ to reach minimum specified voltage (power ramps must be monotonic). | 0.05    | -       | 5       | ms   |

# Electrical Characteristics

$V_{DDX} = 3.3V \pm 5\%$ ,  $2.5V \pm 5\%$ ,  $1.8V \pm 5\%$ ,  $T_A = -40^{\circ}C$  to  $+85^{\circ}C$  unless stated otherwise.

**Table 8. Common Electrical Characteristics**

| Parameter                                                        | Symbol     | Conditions                                   | Minimum                 | Typical | Maximum           | Unit       | Notes |
|------------------------------------------------------------------|------------|----------------------------------------------|-------------------------|---------|-------------------|------------|-------|
| Input Frequency                                                  | $f_{IN}$   | Crystal input frequency.                     | 8                       | -       | 50                | MHz        | 1     |
|                                                                  |            | CLKIN input frequency.                       | 1                       | -       | 240               | MHz        | 5     |
| Output Frequency (OUT[3:0])                                      | $f_{OUT}$  | Differential clock output (LVDS/LP-HCSL).    | 1                       | -       | 325               | MHz        | -     |
|                                                                  |            | Single-ended clock output (LVCMOS).          | 1                       | -       | 200               | MHz        | -     |
| Output Frequency (OUT[1:0])                                      |            | Spread spectrum or fractional configuration. | 1                       | -       | 156.25            | MHz        | 6     |
| VCO Frequency                                                    | $f_{VCO}$  | VCO operating frequency range.               | 2400                    | 2500    | 2600              | MHz        | -     |
| Loop Bandwidth                                                   | $f_{BW}$   | Input frequency = 25MHz.                     | 0.06                    | -       | 0.9               | MHz        | -     |
| Input High Voltage                                               | $V_{IH}$   | SEL[1:0].                                    | $0.7 \times V_{DDD}$    | -       | $V_{DDD} + 0.3$   | V          | -     |
| Input Low Voltage                                                | $V_{IL}$   | SEL[1:0].                                    | GND - 0.3               | -       | 0.8               | V          | -     |
| Input High Voltage                                               | $V_{IH}$   | REF/SEL_I2C#.                                | $0.65 \times V_{DDREF}$ | -       | $V_{DDREF} + 0.3$ | V          | -     |
| Input Low Voltage                                                | $V_{IL}$   | REF/SEL_I2C#.                                | -0.3                    | -       | 0.4               | V          | -     |
| Input High Voltage                                               | $V_{IH}$   | XIN/CLKIN.                                   | 0.8                     | -       | 1.2               | V          | -     |
| Input Low Voltage                                                | $V_{IL}$   | XIN/CLKIN.                                   | -0.3                    | -       | 0.4               | V          | -     |
| Input Rise/Fall Time                                             | $T_R/T_F$  | OEA, OEB (24-pin device only)                | -                       | -       | 10                | ns         | -     |
|                                                                  |            | SEL1/SDA, SEL0/SCL.                          | -                       | -       | 300               | ns         | -     |
| Input Capacitance                                                | $C_{IN}$   | SEL[1:0].                                    | -                       | 3       | 7                 | pF         | -     |
| Internal Pull-up Resistor                                        | $R_{UP}$   | -                                            | 200                     | 237     | 300               | k $\Omega$ | -     |
| Internal Pull-down Resistor                                      | $R_{DOWN}$ | -                                            | 200                     | 237     | 300               | k $\Omega$ | -     |
| Programmable capacitance at XIN and XO (XIN in parallel with XO) | $C_L$      | XIN/CLKIN, XO.                               | 0                       | -       | 8                 | pF         | -     |
| Input Duty Cycle                                                 | t2         | CLKIN, measured at $V_{DDREF}/2$ .           | 40                      | 50      | 60                | %          | -     |
| Output Duty Cycle                                                | t3         | LVCMOS, $f_{OUT} > 156.25MHz$ .              | 40                      | 50      | 60                | %          | -     |
|                                                                  |            | LVCMOS, $f_{OUT} \leq 156.25MHz$ .           | 45                      | 50      | 55                | %          | -     |
|                                                                  |            | LVDS, LP-HCSL outputs.                       | 45                      | 50      | 55                | %          | -     |

**Table 8. Common Electrical Characteristics (Cont.)**

| Parameter               | Symbol | Conditions                                                                                                                                      | Minimum | Typical | Maximum | Unit   | Notes |
|-------------------------|--------|-------------------------------------------------------------------------------------------------------------------------------------------------|---------|---------|---------|--------|-------|
| Clock Jitter (9FGV1004) | t6     | Cycle-to-cycle jitter (Peak-to-Peak), See "Test Frequencies for Jitter Measurements" for configurations.                                        | -       | 27      | -       | ps     | 4     |
|                         |        | Reference clock RMS phase jitter (12kHz to 5MHz integration range). See "Test Frequencies for Jitter Measurements" for configurations.          | -       | 250     | -       | fs rms | 4     |
|                         |        | OUTx RMS phase jitter(12kHz to 20MHz integration range) differential output. See "Test Frequencies for Jitter Measurements" for configurations. | -       | 267     | -       | fs rms | 4     |
| Clock Jitter (9FGV1008) | t6     | Cycle-to-cycle jitter (Peak-to-Peak), See "Test Frequencies for Jitter Measurements" for configurations.                                        | -       | 27      | -       | ps     | 4     |
|                         |        | Reference clock RMS phase jitter (12kHz to 5MHz integration range). See "Test Frequencies for Jitter Measurements" for configurations.          | -       | 317     | -       | fs rms | 4     |
|                         |        | OUTx RMS phase jitter(12kHz to 20MHz integration range) differential output. See "Test Frequencies for Jitter Measurements" for configurations. | -       | 224     | -       | fs rms | 4     |
| Output Skew (9FGV1004)  | t7     | Skew between the same frequencies, with outputs using the same driver format.                                                                   | -       | 34      | -       | ps     | 7     |
| Lock Time               | t8a    | PLL outputs valid from VDDs reaching 1.5V.                                                                                                      | -       | 5       | 10      | ms     | 2,3   |
|                         | t8b    | REF outputs valid from VDDs reaching 1.5V.                                                                                                      | -       | 5       | 11      | ms     | 2,3   |

<sup>1</sup> Practical lower frequency is determined by loop filter settings.

<sup>2</sup> Includes loading the configuration bits from OTP to registers when the configuration number is changed.

<sup>3</sup> Actual PLL lock time depends on the loop configuration.

<sup>4</sup> Actual jitter is configuration dependent. These values are representative of what the device can achieve.

<sup>5</sup> Input doubler off. Maximum input frequency with input doubler on is 160MHz.

<sup>6</sup> With internal low pass filter enabled. When disabled, maximum frequency is 325MHz.

<sup>7</sup> 9FGV1004 OUT0 and OUT1.

**Table 9. Test Frequencies for Jitter Measurements**

| Device                 | XIN/CLKIN | OUT0 | OUT1 | OUT2   | OUT3   | Unit | Notes |
|------------------------|-----------|------|------|--------|--------|------|-------|
| 9FGV1004<br>9FGV1004Q5 | 50        | 100  |      | 125.00 | 156.25 | MHZ  | 1,2,3 |
| Device                 | XIN/CLKIN | OUT0 | OUT1 | OUT2   | OUT3   | Unit | Notes |
| 9FGV1008<br>9FGV1008Q5 | 50        | 100  |      | 156.25 |        | MHZ  | 1,2,3 |

<sup>1</sup> All outputs measured with 100MHz outputs both spreading and non-spreading.

<sup>2</sup> Outputs configured as LP-HCSL or LVDS with REF output off unless noted.

<sup>3</sup> This configuration used for 12kHz–20MHz OUT phase jitter measurement. REF off, SSC off.

**Table 10. LVCMOS Output Electrical Characteristics**

| Parameter                    | Symbol     | Conditions                                                                         | Minimum              | Typical | Maximum   | Unit     | Notes |
|------------------------------|------------|------------------------------------------------------------------------------------|----------------------|---------|-----------|----------|-------|
| Slew Rate                    | $S_R$      | 3.3V $\pm$ 5%, 20% to 80% of $V_{DDO}$<br>(output load = 4.7pF).                   | 2.6                  | 3.7     | 4.7       | V/ns     | -     |
|                              |            | 2.5V $\pm$ 5%, 20% to 80% of $V_{DDO}$<br>(output load = 4.7pF).                   | 1.5                  | 2.4     | 4.7       | V/ns     | -     |
|                              |            | 1.8V $\pm$ 5%, 20% to 80% of $V_{DDO}$<br>(output load = 4.7pF).                   | 1.0                  | 1.7     | 3.2       | V/ns     | -     |
| Output High Voltage          | $V_{OH}$   | $I_{OH}$ = -15mA at 3.3V.<br>$I_{OH}$ = -12mA at 2.5V.<br>$I_{OH}$ = -8mA at 1.8V. | $0.8 \times V_{DDO}$ | -       | $V_{DDO}$ | V        | -     |
| Output Low Voltage           | $V_{OL}$   | $I_{OL}$ = 15mA at 3.3V.<br>$I_{OL}$ = 12mA at 2.5V.<br>$I_{OL}$ = 8mA at 1.8V.    | -                    | 0.22    | 0.4       | V        | -     |
| Output Leakage Current       | $I_{OZDD}$ | Outputs tri-stated, $V_{DDO}$ , $V_{DDREF}$ = 3.465V.                              | -                    | 0       | 5         | $\mu$ A  | -     |
| CMOS Output Driver Impedance | $R_{OUT}$  | $T_A$ = 25°C.                                                                      | -                    | 17      |           | $\Omega$ | -     |

**Table 11. LVDS Output Electrical Characteristics**

| Parameter                                                                | Symbol          | Minimum | Typical | Maximum | Unit | Notes |
|--------------------------------------------------------------------------|-----------------|---------|---------|---------|------|-------|
| Differential Output Voltage for the TRUE Binary State                    | $V_{OT}(+)$     | 247     | 328     | 454     | mV   | -     |
| Differential Output Voltage for the FALSE Binary State                   | $V_{OT}(-)$     | -454    | -332    | -247    | mV   | -     |
| Change in $V_{OT}$ between Complementary Output States                   | $\Delta V_{OT}$ |         |         | 50      | mV   | -     |
| Output Common Mode Voltage (Offset Voltage) at 3.3V +5% and 2.5V +5%     | $V_{OS}$        | 1.125   | 1.19    | 1.55    | V    | -     |
| Output Common Mode Voltage (Offset Voltage) at 1.8V +5%                  | $V_{OS}$        | 0.8     | 0.86    | 0.95    | V    | -     |
| Change in $V_{OS}$ between Complementary Output States                   | $\Delta V_{OS}$ |         | 0       | 50      | mV   | -     |
| Outputs Short Circuit Current, $V_{OUT+}$ or $V_{OUT-}$ = 0V or $V_{DD}$ | $I_{OS}$        |         | 6       | 12      | mA   | -     |
| Differential Outputs Short Circuit Current, $V_{OUT+} = V_{OUT-}$        | $I_{OSD}$       |         | 3       | 12      | mA   | -     |

**Table 11. LVDS Output Electrical Characteristics (Cont.)**

| Parameter                      | Symbol | Minimum | Typical | Maximum | Unit | Notes |
|--------------------------------|--------|---------|---------|---------|------|-------|
| Rise Times Tested at 20% – 80% | $T_R$  | -       | 257     | 375     | ps   | -     |
| Fall Times Tested at 80% – 20% | $T_F$  | -       | 287     | 375     | ps   | -     |

**Table 12. Low-Power (LP) Push-Pull HCSL Differential Outputs**

$V_{DDO} = 3.3V \pm 5\%$ ,  $2.5V \pm 5\%$ ,  $1.8V \pm 5\%$ ,  $T_A = -40^\circ C$  to  $+85^\circ C$  unless stated otherwise.

| Parameter                     | Symbol             | Conditions                                   | Minimum | Typical | Maximum | Unit | Notes      |
|-------------------------------|--------------------|----------------------------------------------|---------|---------|---------|------|------------|
| Slew Rate                     | $T_{R/F}$          | Scope averaging on.                          | 1       | 2.5     | 4       | V/ns | 2,3,16     |
| Slew Rate Matching            | $\Delta T_{R/F}$   |                                              | -       | 9       | 20      | %    | 1,14,16    |
| Crossing Voltage (abs)        | $V_{CROSS}$        | Scope averaging off.                         | 250     | 424     | 550     | mV   | 1,4,5,16   |
| Crossing Voltage (var)        | $\Delta V_{CROSS}$ | Scope averaging off.                         | -       | 16      | 140     | mV   | 1,4,9,16   |
| Average Clock Period Accuracy | $T_{PERIOD\_AVG}$  | Outputs set to 100MHz for PCIe applications. | -100    | 0       | +2600   | ppm  | 2,10,12,13 |
| Absolute Period               | $T_{PERIOD\_ABS}$  | Includes jitter and spread modulation.       | 9.949   | 10      | 10.101  | ns   | 2,6        |
| Absolute Maximum Voltage      | $V_{MAX}$          | Includes 300mV of overshoot (Vovs).          | 660     | 808     | 1150    | mV   | 1,7,15     |
| Absolute Minimum Voltage      | $V_{MIN}$          | Includes -300mV of undershoot (Vuds).        | -300    | -54     | 150     | mV   | 1,8,15     |

<sup>1</sup> Measured from single-ended waveform.

<sup>2</sup> Measured from differential waveform.

<sup>3</sup> Measured from -150mV to +150mV on the differential waveform (derived from REFCLK+ minus REFCLK-). The signal must be monotonic through the measurement region for rise and fall time. The 300mV measurement window is centered on the differential zero crossing.

<sup>4</sup> Measured at crossing point where the instantaneous voltage value of the rising edge of REFCLK+ equals the falling edge of REFCLK-.

<sup>5</sup> Refers to the total variation from the lowest crossing point to the highest, regardless of which edge is crossing. Refers to all crossing points for this measurement.

<sup>6</sup> Defines as the absolute minimum or maximum instantaneous period. This includes cycle-to-cycle jitter, relative ppm tolerance, and spread spectrum modulation.

<sup>7</sup> Defined as the maximum instantaneous voltage including overshoot.

<sup>8</sup> Defined as the minimum instantaneous voltage including undershoot.

<sup>9</sup> Defined as the total variation of all crossing voltages of rising REFCLK+ and falling REFCLK-. This is the maximum allowed variance in  $V_{CROSS}$  for any particular system.

<sup>10</sup> Refer to Section 8.6 of the PCI Express Base Specification, Revision 4.0 for information regarding PPM considerations.

<sup>11</sup> System board compliance measurements must use the test load. REFCLK+ and REFCLK- are to be measured at the load capacitors CL. Single-ended probes must be used for measurements requiring single-ended measurements. Either single-ended probes with math or differential probe can be used for differential measurements. Test load  $C_L = 2pF$ .

<sup>12</sup> PCIe Gen1 through Gen4 specify  $\pm 300ppm$  frequency tolerances. The PhiClock devices already meet the tighter  $\pm 100ppm$  frequency tolerances proposed for PCIe Gen5 and required by most servers.

<sup>13</sup> "ppm" refers to parts per million and is a DC absolute period accuracy specification. 1ppm is 1/1,000,000th of 100.000000MHz exactly or 100Hz. For 100ppm, then we have an error budget of  $100Hz/ppm \times 100ppm = 10kHz$ . The period is to be measured with a frequency counter with measurement window set to 100ms or greater. The  $\pm 100ppm$  applies to systems that do not employ Spread Spectrum Clocking, or that use common clock source. For systems employing Spread Spectrum Clocking, there is an additional 2,500ppm nominal shift in maximum period resulting from the 0.5% down spread resulting in a maximum average period specification of +2,600ppm for Common Clock Architectures. Separate Reference Clock Architectures may have a lower allowed spread percentage.

<sup>14</sup> Matching applies to rising edge rate for REFCLK+ and falling edge rate for REFCLK-. It is measured using a  $\pm 75\text{mV}$  window centered on the median cross point where REFCLK+ rising meets REFCLK- falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations. The rise edge rate of REFCLK+ should be compared to the fall edge rate of REFCLK-; the maximum allowed difference should not exceed 20% of the slowest edge rate.

<sup>15</sup> At default amplitude settings.

<sup>16</sup> Guaranteed by design and characterization.

**Table 13. Filtered Phase Jitter Parameters – PCIe Common Clocked (CC) Architectures**

T<sub>AMB</sub> = over the specified operating range. Supply Voltages per normal operation conditions; see [Test Loads](#) for loading conditions.

| Parameter         | Symbol                    | Conditions                                                                                          | Minimum | Typical | Maximum | Industry Limits | Unit     | Notes   |
|-------------------|---------------------------|-----------------------------------------------------------------------------------------------------|---------|---------|---------|-----------------|----------|---------|
| PCIe Phase Jitter | t <sub>jphPCIeG1-CC</sub> | PCIe Gen1.                                                                                          | -       | 24      | 43      | 86              | ps (p-p) | 1,2,3   |
|                   | t <sub>jphPCIeG2-CC</sub> | PCIe Gen2 Low Band<br>10kHz < f < 1.5MHz<br>(PLL BW of 5–16MHz, 8–16MHz,<br>CDR = 5MHz).            | -       | 0.7     | 1.4     | 3               | ps (rms) | 1,2     |
|                   |                           | PCIe Gen2 High Band<br>1.5MHz < f < Nyquist (50MHz)<br>(PLL BW of 5–16MHz, 8–16MHz,<br>CDR = 5MHz). | -       | 1.8     | 2.6     | 3.1             | ps (rms) | 1,2     |
|                   | t <sub>jphPCIeG3-CC</sub> | PCIe Gen3<br>(PLL BW of 2–4MHz, 2–5MHz,<br>CDR = 10MHz).                                            | -       | 0.44    | 0.65    | 1               | ps (rms) | 1,2     |
|                   | t <sub>jphPCIeG4-CC</sub> | PCIe Gen4 (SSC off)<br>(PLL BW of 2–4MHz, 2–5MHz,<br>CDR = 10MHz).                                  | -       | 0.30    | 0.44    | 0.5             | ps (rms) | 1,2,6,7 |

**Table 14. Filtered Phase Jitter Parameters – PCIe Independent Reference (IR) Architectures**

T<sub>AMB</sub> = over the specified operating range. Supply Voltages per normal operation conditions; see [Test Loads](#) for loading conditions.

| Parameter         | Symbol                      | Conditions                                              | Minimum | Typical | Maximum | Industry Limits | Unit     | Notes     |
|-------------------|-----------------------------|---------------------------------------------------------|---------|---------|---------|-----------------|----------|-----------|
| PCIe Phase Jitter | t <sub>jphPCIeG2-SRnS</sub> | PCIe Gen2 (-0.5% SSC)<br>(PLL BW of 16MHz, CDR = 5MHz). | -       | 1.2     | 1.53    | 2               | ps (rms) | 1,2,4,5   |
|                   | t <sub>jphPCIeG3-SRnS</sub> | PCIe Gen3 (SSC off)<br>(PLL BW of 2–4MHz, CDR = 10MHz). | -       | 0.37    | 0.45    | 0.7             | ps (rms) | 1,2,4,5,6 |

**Notes for all PCIe Filtered Phase Jitter tables:**

<sup>1</sup> Applies to all differential outputs, guaranteed by design and characterization.

<sup>2</sup> Based on PCIe Base Specification Rev4.0 version 1.0. See <http://www.pcisig.com> for latest specifications.

<sup>3</sup> Sample size of at least 100K cycles. This figure extrapolates to 108ps pk-pk at 1M cycles for a BER of  $10^{-12}$ .

<sup>4</sup> IR is the new name for Separate Reference Independent Spread (SRIS) and Separate Reference no Spread (SRNS) PCIe clock architectures.

<sup>5</sup> According to the PCIe Base Specification Rev4.0 version 1.0, the jitter transfer functions and corresponding jitter limits are not defined for the IR clock architecture. Widely accepted *industry* limits using widely accepted *industry* filters are used to populate this table. The PCIe Base Specification Rev5.0 is expected to resolve this.

<sup>6</sup> For improved PCIe performance, including PCIe Gen5, see application note [AN1001](#).

<sup>7</sup> SSC off.

**Table 15. Current Consumption—9FGV1004**

$V_{DDO} = 3.3V \pm 5\%$ ,  $2.5V \pm 5\%$ ,  $1.8V \pm 5\%$ ,  $T_A = -40^\circ C$  to  $+85^\circ C$  unless stated otherwise.

| Parameter                            | Symbol              | Conditions                                         | Minimum | Typical | Maximum | Unit | Notes |
|--------------------------------------|---------------------|----------------------------------------------------|---------|---------|---------|------|-------|
| V <sub>DDREF</sub> Supply Current    | I <sub>DDREF</sub>  | 25MHz REFCLK.                                      | -       | 7       | 11      | mA   |       |
| Core Supply Current                  | I <sub>DDCORE</sub> | 2500MHz VCO, 25MHz REFCLK.                         | -       | 30.5    | 42      | mA   | 3     |
| V <sub>DDA</sub> Supply Current      | I <sub>DDA</sub>    | I <sub>DDA</sub> – 2500MHz VCO, 25MHz REFCLK.      | -       | 25.9    | 32      | mA   | 3     |
| V <sub>DDD</sub> Supply Current      | I <sub>DDD</sub>    | I <sub>DDD</sub> – 2500MHz VCO, 25MHz REFCLK.      | -       | 4.6     | 10      | mA   | 3     |
| Output Buffer Supply Current (VDDO3) | I <sub>DDOx</sub>   | LVDS, 325MHz                                       | -       | 18      | 24      | mA   | 2     |
|                                      |                     | LP-HCSL, 100MHz                                    | -       | 12      | 21      | mA   | 2     |
|                                      |                     | LVC MOS, 50MHz                                     | -       | 14      | 19      | mA   | 1,2   |
|                                      |                     | LVC MOS, 200MHz                                    | -       | 21      | 35      | mA   | 1,2   |
| Output Buffer Supply Current (VDDO2) |                     | LVDS, 325MHz                                       | -       | 18      | 24      | mA   | 2     |
|                                      |                     | LP-HCSL, 100MHz                                    | -       | 16      | 21      | mA   | 2     |
|                                      |                     | LVC MOS, 50MHz                                     | -       | 14      | 19      | mA   | 1,2   |
|                                      |                     | LVC MOS, 200MHz                                    | -       | 21      | 35      | mA   | 1,2   |
| Output Buffer Supply Current (VDDO1) |                     | LVDS, 325MHz, SSC Off                              | -       | 8       | 11      | mA   | 2     |
|                                      |                     | LP-HCSL, 100MHz, SSC Off                           | -       | 6       | 8       | mA   | 2     |
|                                      |                     | LP-HCSL, 100MHz, SSC On                            | -       | 14      | 18      | mA   | 2     |
|                                      |                     | LVC MOS, 50MHz, SSC Off                            | -       | 5       | 7       | mA   | 1,2   |
|                                      |                     | LVC MOS, 50MHz, SSC On                             | -       | 9       | 12      | mA   | 1,2   |
|                                      |                     | LVC MOS, 200MHz, SSC Off                           | -       | 13      | 24      | mA   | 1,2   |
| Output Buffer Supply Current (VDDO0) |                     | LVDS, 325MHz                                       | -       | 16      | 21      | mA   | 2     |
|                                      |                     | LP-HCSL, 100MHz                                    | -       | 15      | 18      | mA   | 2     |
|                                      | LVC MOS, 50MHz      | -                                                  | 13      | 17      | mA      | 1,2  |       |
|                                      | LVC MOS, 200MHz     | -                                                  | 21      | 34      | mA      | 1,2  |       |
| Total Power Down Current             | I <sub>DDPD</sub>   | Programmable outputs in HCSL mode, B37[0] = 0.     | -       | 20      | 26      | mA   | 1,2   |
|                                      |                     | Programmable outputs in LVDS mode, B37[0] = 0.     | -       | 31      | 43      | mA   | 1,2   |
|                                      |                     | Programmable outputs in LVC MOS1 mode, B37[0] = 0. | -       | 16      | 20      | mA   | 1,2   |

<sup>1</sup> Single CMOS driver active for each output pair.

<sup>2</sup> See [Test Loads](#) for details.

<sup>3</sup>  $I_{DDCORE} = I_{DDA} + I_{DDD}$ .

**Table 16. Current Consumption–9FGV1008**
 $V_{DDO} = 3.3V \pm 5\%$ ,  $2.5V \pm 5\%$ ,  $1.8V \pm 5\%$ ,  $T_A = -40^\circ C$  to  $+85^\circ C$  unless stated otherwise.

| Parameter                               | Symbol              | Conditions                                         | Minimum | Typical | Maximum | Unit | Notes |
|-----------------------------------------|---------------------|----------------------------------------------------|---------|---------|---------|------|-------|
| V <sub>DDREF</sub> Supply Current       | I <sub>DDREF</sub>  | 50MHz REFCLK.                                      | -       | 5       | 7       | mA   | -     |
| Core Supply Current                     | I <sub>DDCORE</sub> | 2500MHz VCO, SSC off.                              | -       | 32      | 45      | mA   | 3     |
|                                         |                     | 2500MHz VCO, SSC on.                               | -       | 39      | 56      | mA   | 3     |
| Output Buffer Supply Current<br>(VDDO1) | I <sub>DDOx</sub>   | LVDS, 325MHz.                                      | -       | 18      | 22      | mA   | 2     |
|                                         |                     | LP-HCSL, 100MHz.                                   | -       | 16      | 21      | mA   | 2     |
|                                         |                     | LVC MOS, 50MHz.                                    | -       | 14      | 18      | mA   | 1,2   |
|                                         |                     | LVC MOS, 200MHz.                                   | -       | 22      | 34      | mA   | 1,2   |
| Output Buffer Supply Current<br>(VDDO0) |                     | LVDS, 325MHz.                                      | -       | 16      | 21      | mA   | 2     |
|                                         |                     | LP-HCSL.                                           | -       | 16      | 20      | mA   | 2     |
|                                         |                     | LVC MOS, 50MHz.                                    | -       | 13      | 18      | mA   | 1,2   |
|                                         |                     | LVC MOS, 200MHz.                                   | -       | 21      | 33      | mA   | 1,2   |
| Total Power Down Current                | I <sub>DDPD</sub>   | Programmable outputs in HCSL mode, B37[0] = 0.     | -       | 19      | 25      | mA   | 1,2   |
|                                         |                     | Programmable outputs in LVDS mode, B37[0] = 0.     | -       | 25      | 35      | mA   | 1,2   |
|                                         |                     | Programmable outputs in LVC MOS1 mode, B37[0] = 0. | -       | 17      | 23      | mA   | 1,2   |

<sup>1</sup> Single CMOS driver active for each output pair.

<sup>2</sup> See [Test Loads](#) for details.

<sup>3</sup>  $I_{DDCORE} = I_{DDA} + I_{DDD} + I_{DDAO}$ .

**Table 17. 9FGV1004C/9FGV1008C Spread Spectrum Programmability**

| Parameter     | Symbol        | Conditions                              | Minimum    | Typical | Maximum   | Unit |
|---------------|---------------|-----------------------------------------|------------|---------|-----------|------|
| Mod Frequency | $f_{MODPCle}$ | PCle Compliant -0.5% spread modulation. | 30         | 31.5    | 33        | kHz  |
| Mod Frequency | $f_{MOD}$     | Modulation frequency.                   | 30         | -       | 63        | kHz  |
| Spread%       | SSC%          | Spread amount – down spread.            | -0.1       | -       | -3        | %    |
| Spread%       | SSC%          | Spread amount – center spread.          | $\pm 0.05$ | -       | $\pm 1.5$ | %    |



# I<sup>2</sup>C Bus Characteristics

**Table 18. I<sup>2</sup>C Bus DC Characteristics**

| Parameter             | Symbol    | Conditions      | Minimum               | Typical | Maximum              | Unit    |
|-----------------------|-----------|-----------------|-----------------------|---------|----------------------|---------|
| Input High Level      | $V_{IH}$  | -               | $0.7 \times V_{DDD}$  | -       | -                    | V       |
| Input Low Level       | $V_{IL}$  | -               | -                     | -       | $0.3 \times V_{DDD}$ | V       |
| Hysteresis of Inputs  | $V_{HYS}$ | -               | $0.05 \times V_{DDD}$ | -       | -                    | V       |
| Input Leakage Current | $I_{IN}$  | -               | -1                    | -       | 30                   | $\mu A$ |
| Output Low Voltage    | $V_{OL}$  | $I_{OL} = 3mA.$ | -                     | -       | 0.4                  | V       |

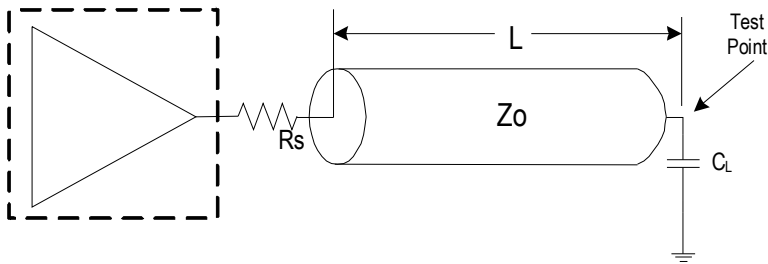
**Table 19. I<sup>2</sup>C Bus AC Characteristics**

| Parameter                                | Symbol         | Conditions | Minimum               | Typical | Maximum | Unit    |
|------------------------------------------|----------------|------------|-----------------------|---------|---------|---------|
| Serial Clock Frequency (SCL)             | $F_{SCLK}$     | -          | 10                    | -       | 400     | kHz     |
| Bus free time between STOP and START     | $t_{BUF}$      | -          | 1.3                   | -       | -       | $\mu s$ |
| Setup Time, START                        | $t_{SU:START}$ | -          | 0.6                   | -       | -       | $\mu s$ |
| Hold Time, START                         | $t_{HD:START}$ | -          | 0.6                   | -       | -       | $\mu s$ |
| Setup Time, Data Input (SDA)             | $t_{SU:DATA}$  | -          | 0.1                   | -       | -       | $\mu s$ |
| Hold Time, Data Input (SDA) <sup>1</sup> | $t_{HD:DATA}$  | -          | 0                     | -       | -       | $\mu s$ |
| Output Data Valid from Clock             | $t_{OVD}$      | -          | -                     | -       | 0.9     | $\mu s$ |
| Capacitive Load for Each Bus Line        | $C_B$          | -          | -                     | -       | 400     | pF      |
| Rise Time, Data and Clock (SDA, SCL)     | $t_R$          | -          | $20 + 0.1 \times C_B$ | -       | 300     | ns      |
| Fall Time, Data and Clock (SDA, SCL)     | $t_F$          | -          | $20 + 0.1 \times C_B$ | -       | 300     | ns      |
| High Time, Clock (SCL)                   | $t_{HIGH}$     | -          | 0.6                   | -       | -       | $\mu s$ |
| Low Time, Clock (SCL)                    | $t_{LOW}$      | -          | 1.3                   | -       | -       | $\mu s$ |
| Setup Time, STOP                         | $t_{SU:STOP}$  | -          | 0.6                   | -       | -       | $\mu s$ |

<sup>1</sup> A device must internally provide a hold time of at least 300ns for the SDA signal (referred to the  $V_{IH(MIN)}$  of the SCL signal) to bridge the undefined region of the falling edge of SCL.

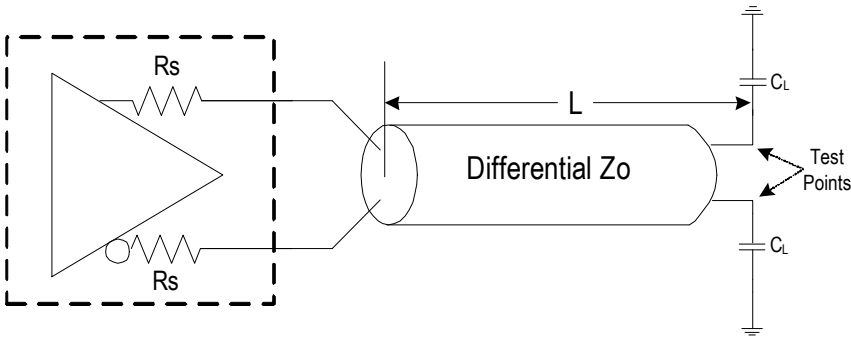
Test Loads

Figure 4. LVCMOS AC/DC Test Load



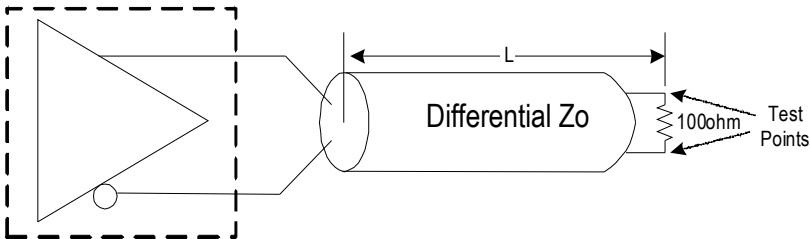
| Rs  | Zo  | L        | CL    |
|-----|-----|----------|-------|
| 33Ω | 50Ω | 5 inches | 4.7pF |

Figure 5. LP-HCSL AC/DC Test Load  
(Standard PCIe source-terminated test load)



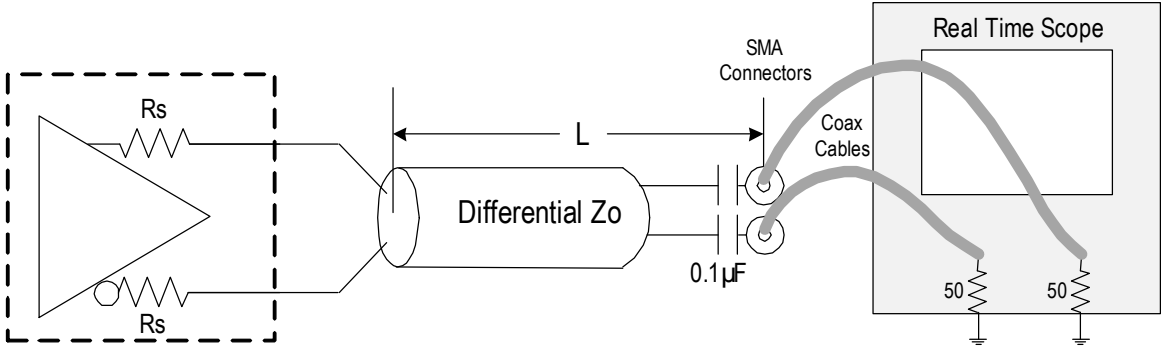
| Rs       | Zo   | L        | CL  |
|----------|------|----------|-----|
| Internal | 100Ω | 5 inches | 2pF |
| Internal | 85Ω  | 5 inches | 2pF |

Figure 6. LVDS AC/DC Test Load



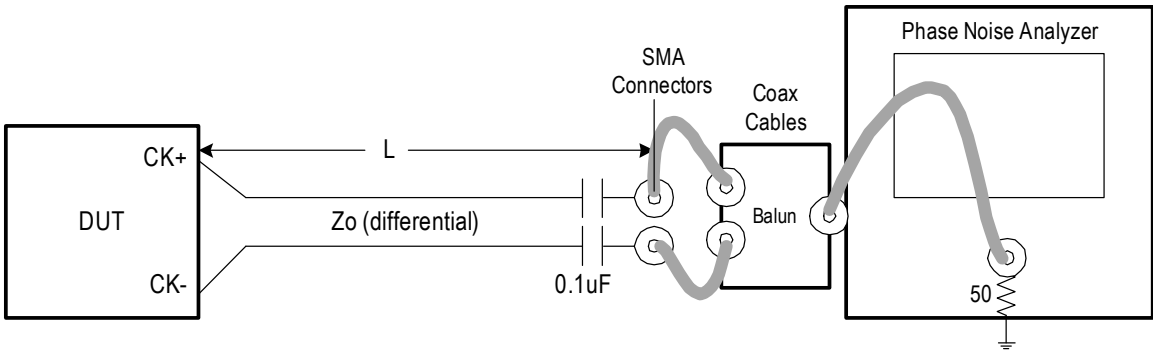
| Rs  | Zo   | L        | CL  |
|-----|------|----------|-----|
| N/A | 100Ω | 5 inches | N/A |

Figure 7. Test Setup for PCIe Measurement Using a Real-Time Scope



| $R_s$    | $Z_o$       | $L$      | $C_L$ |
|----------|-------------|----------|-------|
| Internal | $100\Omega$ | 5 inches | N/A   |

Figure 8. Test Setup for PCIe Measurement Using a Phase Noise Analyzer



| $R_s$    | $Z_o$       | $L$      | $C_L$ |
|----------|-------------|----------|-------|
| Internal | $100\Omega$ | 5 inches | N/A   |

## Crystal Characteristics

**Table 20. Recommended Crystal Characteristics**

| Parameter                                                         | Value       | Unit        |
|-------------------------------------------------------------------|-------------|-------------|
| Frequency                                                         | 8 – 50      | MHz         |
| Resonance Mode                                                    | Fundamental | -           |
| Frequency Tolerance at 25°C                                       | ±20         | ppm maximum |
| Frequency Stability, REF at 25°C Over Operating Temperature Range | ±20         | ppm maximum |
| Temperature Range (commercial)                                    | 0 to +70    | °C          |
| Temperature Range (industrial)                                    | -40 to +85  | °C          |
| Equivalent Series Resistance (ESR)                                | 50          | Ω maximum   |
| Shunt Capacitance ( $C_0$ )                                       | 7           | pF maximum  |
| Load Capacitance ( $C_L$ )                                        | 8           | pF maximum  |
| Drive Level                                                       | 0.1         | mW maximum  |
| Aging per year                                                    | ±5          | ppm maximum |

## Power Sequencing Recommendations

There is no specific power sequencing requirements and all supply pins can be grouped onto one power rail. Output supplies  $V_{DDREF}$  and  $V_{DDO0}$  must be connected. If OUT0 is used, both pins 9 and 10 must be connected. For more details on output supply registers, see [Table 21](#) and the [9FGV100x Register Descriptions and Programming Guide](#).

**Table 21. Power Supply, Output Clock and Corresponding Register Values**

| Power Supply | Output Clock | Register |
|--------------|--------------|----------|
| $V_{DDO0}$   | OUT1         | 0x0B[7]  |
| $V_{DDO1}$   | OUT2         | 0x08[7]  |
| $V_{DDO2}$   | OUT3         | 0x05[7]  |
| $V_{DDO3}$   | OUT4         | 0x02[7]  |

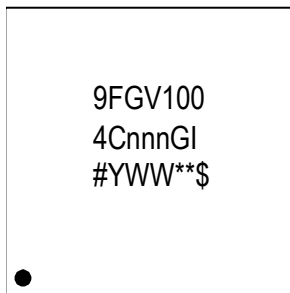
Unused or floating pins are then removed from power sequencing considerations. The power-up times for all VDDs to reach the minimum specified voltage is a minimum of 0.05ms, as seen in [Table 7](#).

## Package Outline Drawings

The package outline drawings are located at the end of this document and are accessible from the Renesas website (see [Ordering Information](#) for POD links). The package information is the most current data available and is subject to change without revision of this document.

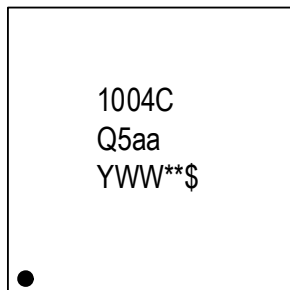
## Marking Diagrams

### 24-VFQFPN



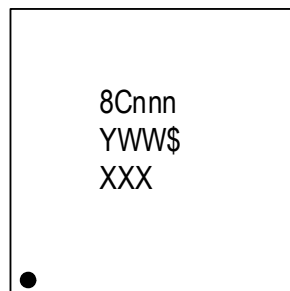
- Lines 1 and 2 are the truncated part number.
- Line 3:
  - “#” denotes the stepping number.
  - “YWW” denotes the last digits of the year and week the part was assembled.
  - “\*\*” denotes the lot sequence.
  - “\$” denotes the mark code.

### 24-LGA (with internal crystal)



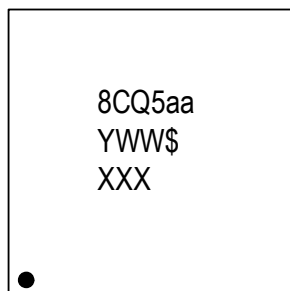
- Lines 1 and 2 are the truncated part number.
- Line 3:
  - “YWW” denotes the last digits of the year and week the part was assembled.
  - “\*\*” denotes the lot sequence.
  - “\$” denotes the mark code.

### 16-LGA



- Line 1 is the truncated part number.
- Line 2:
  - “YWW” denotes the last digits of the year and week the part was assembled.
  - “\$” denotes the mark code.
- Line 3:
  - “XXX” denotes the last three characters of the assembly lot number.

### 16-LGA (with internal crystal)



- Line 1 is the truncated part number.
- Line 2:
  - “YWW” denotes the last digits of the year and week the part was assembled.
  - “\$” denotes the mark code.
- Line 3:
  - “XXX” denotes the last three characters of the assembly lot number.

## Standard Configurations

**Table 22. 9FGV1004C/9FGV1008C Standard Configurations**

| Supply Voltage—all pins (V) | Output Impedance (ohms) | Number of PCIe Clock Outputs | XTAL Frequency (MHz) | Orderable Part Number (Bulk) | Orderable Part Number (Tape and Reel) |
|-----------------------------|-------------------------|------------------------------|----------------------|------------------------------|---------------------------------------|
| 3.3 and 1.8                 | 100 (LP-HCSL)           | 4                            | 50 – external        | 9FGV1004C001NBGI             | 9FGV1004C001NBGI8                     |
|                             |                         |                              | 50 – internal        | 9FGV1004CQ501LTGI            | 9FGV1004CQ501LTGI8                    |
|                             |                         | 2                            | 50 – external        | 9FGV1008C001LTGI             | 9FGV1008C001LTGI8                     |
|                             |                         |                              | 50 – internal        | 9FGV1008CQ501LTGI            | 9FGV1008CQ501LTGI8                    |

**Table 23. Common Features of 9FGV1004C/9FGV1008C Standard Configurations**

| Configuration | 9FGV1004 Output | 9FGV1008 Output | Output Frequency (MHz) | Supply Voltage (V) | Output Type | Ref Outputs |
|---------------|-----------------|-----------------|------------------------|--------------------|-------------|-------------|
| 0             | OUT0            | OUT0            | 100                    | 1.8                | LP-HCSL     | OFF         |
|               | OUT1            | -               | 100                    | 1.8                | LP-HCSL     |             |
|               | OUT2            | OUT1            | 125                    | 1.8                | LVDS        |             |
|               | OUT3            | -               | 50                     | 1.8                | LP-HCSL     |             |
| 1             | OUT0            | OUT0            | 100                    | 1.8                | LP-HCSL     | OFF         |
|               | OUT1            | -               | 100                    | 1.8                | LP-HCSL     |             |
|               | OUT2            | OUT1            | 156.25                 | 1.8                | LVDS        |             |
|               | OUT3            | -               | 50                     | 1.8                | LP-HCSL     |             |
| 2             | OUT0            | OUT0            | 100                    | 3.3                | LP-HCSL     | OFF         |
|               | OUT1            | -               | 100                    | 3.3                | LP-HCSL     |             |
|               | OUT2            | OUT1            | 125                    | 3.3                | LVDS        |             |
|               | OUT3            | -               | 50                     | 3.3                | LP-HCSL     |             |
| 3             | OUT0            | OUT0            | 100                    | 3.3                | LP-HCSL     | OFF         |
|               | OUT1            | -               | 100                    | 3.3                | LP-HCSL     |             |
|               | OUT2            | OUT1            | 156.25                 | 3.3                | LVDS        |             |
|               | OUT3            | -               | 50                     | 3.3                | LP-HCSL     |             |

## Ordering Information

| Orderable Part Number | Package                                         | Carrier Type  | Temperature  | Crystal        |
|-----------------------|-------------------------------------------------|---------------|--------------|----------------|
| 9FGV1004CnnnNBGI      | 4 × 4 mm, 0.5mm pitch <a href="#">24-VFQFPN</a> | Tray          | -40 to +85°C | External       |
| 9FGV1004CnnnNBGI8     | 4 × 4 mm, 0.5mm pitch <a href="#">24-VFQFPN</a> | Tape and Reel | -40 to +85°C | External       |
| 9FGV1004CQ5aaLTGI     | 4 × 4 mm, 0.5mm pitch <a href="#">24-LGA</a>    | Tray          | -40 to +85°C | 50MHz Internal |
| 9FGV1004CQ5aaLTGI8    | 4 × 4 mm, 0.5mm pitch <a href="#">24-LGA</a>    | Tape and Reel | -40 to +85°C | 50MHz Internal |
| 9FGV1008CnnnLTGI      | 3 × 3 mm, 0.5mm pitch <a href="#">16-LGA</a>    | Tray          | -40 to +85°C | External       |
| 9FGV1008CnnnLTGI8     | 3 × 3 mm, 0.5mm pitch <a href="#">16-LGA</a>    | Tape and Reel | -40 to +85°C | External       |
| 9FGV1008CQ5aaLTGI     | 3 × 3 mm, 0.5mm pitch <a href="#">16-LGA</a>    | Tray          | -40 to +85°C | 50MHz Internal |
| 9FGV1008CQ5aaLTGI8    | 3 × 3 mm, 0.5mm pitch <a href="#">16-LGA</a>    | Tape and Reel | -40 to +85°C | 50MHz Internal |

“G” indicates RoHS 6.6 compliance.

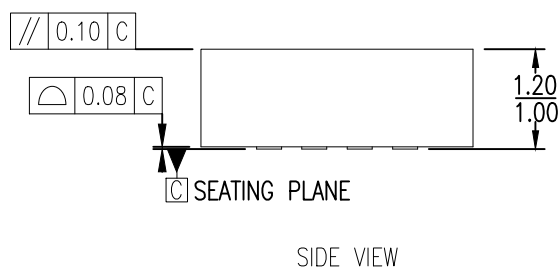
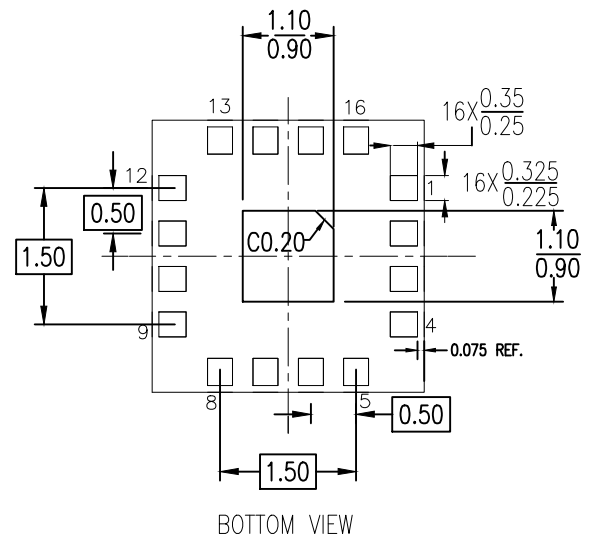
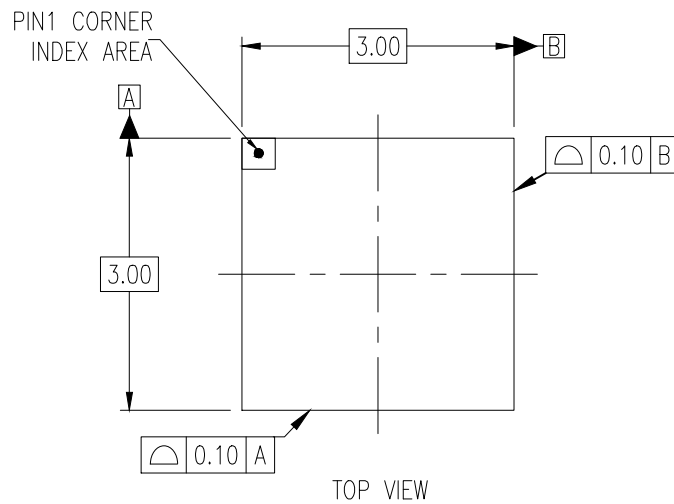
“nnn” are decimal digits indicating a specific configuration.

“aa” are alphanumeric digits indicating a specific configuration.

“Q5” indicates internal 50MHz crystal.

## Revision History

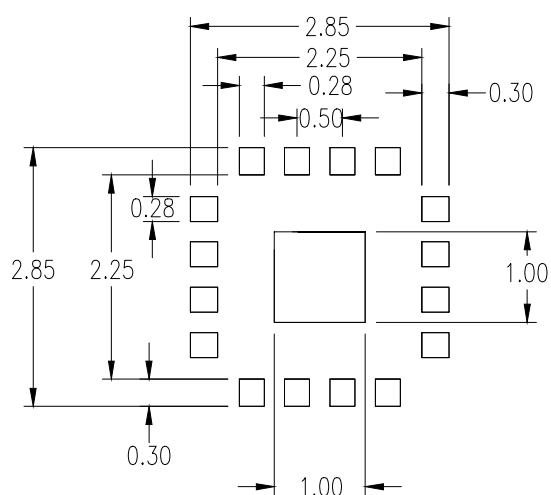
| Revision Date      | Description of Change                                                                                                                                                                                                                                                                                                |
|--------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| October 8, 2025    | <ul style="list-style-type: none"> <li>Updated <math>I_{DDREF}</math> and <math>I_{DDCORE}</math> in <a href="#">Table 15</a>.</li> <li>Added rows for <math>I_{DDA}</math> and <math>I_{DD}</math> in <a href="#">Table 15</a>.</li> <li>Added <a href="#">Power Sequencing Recommendations</a> section.</li> </ul> |
| July 18, 2024      | Updated the 24-LGA POD link to the LTG24T2 package in <a href="#">Ordering Information</a> .                                                                                                                                                                                                                         |
| March 29, 2023     | <ul style="list-style-type: none"> <li>Updated footnote 2 in <a href="#">Table 8</a>.</li> <li>Moved package outline drawings links to Ordering Information.</li> </ul>                                                                                                                                              |
| January 31, 2023   | Updated POD links in <a href="#">Package Outline Drawings</a> .                                                                                                                                                                                                                                                      |
| October 29, 2020   | Updated pin descriptions for VDDAp and VDDDp.                                                                                                                                                                                                                                                                        |
| October 20, 2020   | Added Test Loads section and diagrams.                                                                                                                                                                                                                                                                               |
| September 28, 2020 | Added Standard Configurations section and tables.                                                                                                                                                                                                                                                                    |
| September 22, 2020 | Correct all $f_{OUT}$ minimum frequencies from 10MHz to 1MHz in Common Electrical Characteristics table.                                                                                                                                                                                                             |
| August 18, 2020    | Updated 9FGV1008CQ (16-LGA with internal crystal) marking diagram.                                                                                                                                                                                                                                                   |
| August 14, 2020    | Updated Slew Rate 1.8V minimum value from 0.8 to 1.0V/ns.                                                                                                                                                                                                                                                            |
| August 13, 2020    | Updated Carrier Type in Ordering Information table from “Trays” to “Tray”.                                                                                                                                                                                                                                           |
| July 20, 2020      | Corrected internal resistors from pull-up to pull-down on SEL0/SCL and SEL1/SDA pins.                                                                                                                                                                                                                                |
| April 16, 2020     | Initial release.                                                                                                                                                                                                                                                                                                     |



### NOTES:

1. ALL DIMENSIONING AND TOLERANCING CONFORM TO ANSI Y14.5M-1982.
2. ALL DIMENSIONS ARE IN MILLIMETERS.

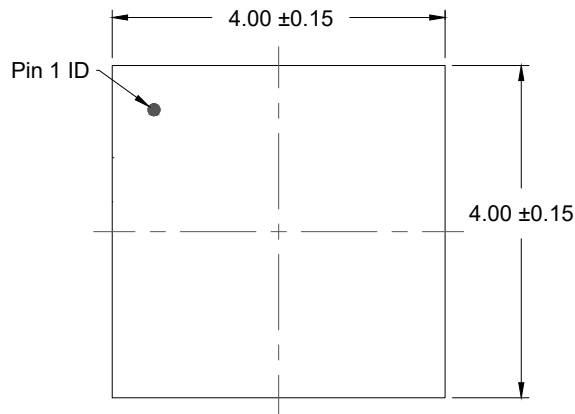




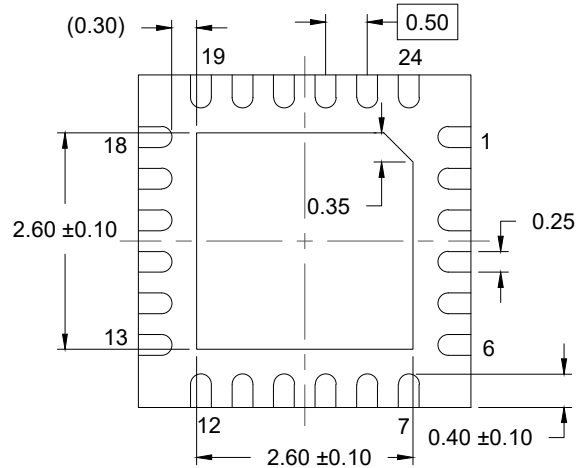
RECOMMENDED LAND PATTERN DIMENSION

NOTES:

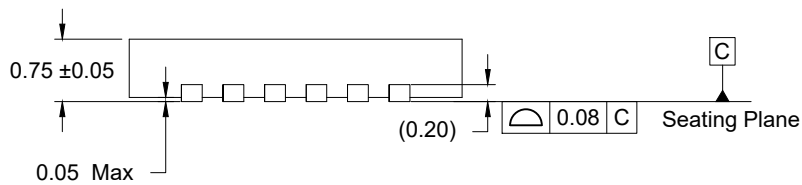
1. ALL DIMENSION ARE IN mm. ANGLES IN DEGREES.
2. TOP DOWN VIEW. AS VIEWED ON PCB.
3. LAND PATTERN RECOMMENDATION PER IPC-7351B GENERIC REQUIREMENT FOR SURFACE MOUNT DESIGN AND LAND PATTERN.



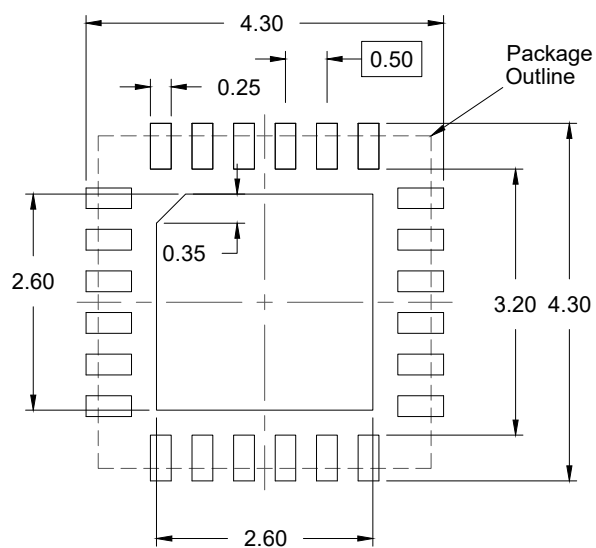
TOP VIEW



BOTTOM VIEW



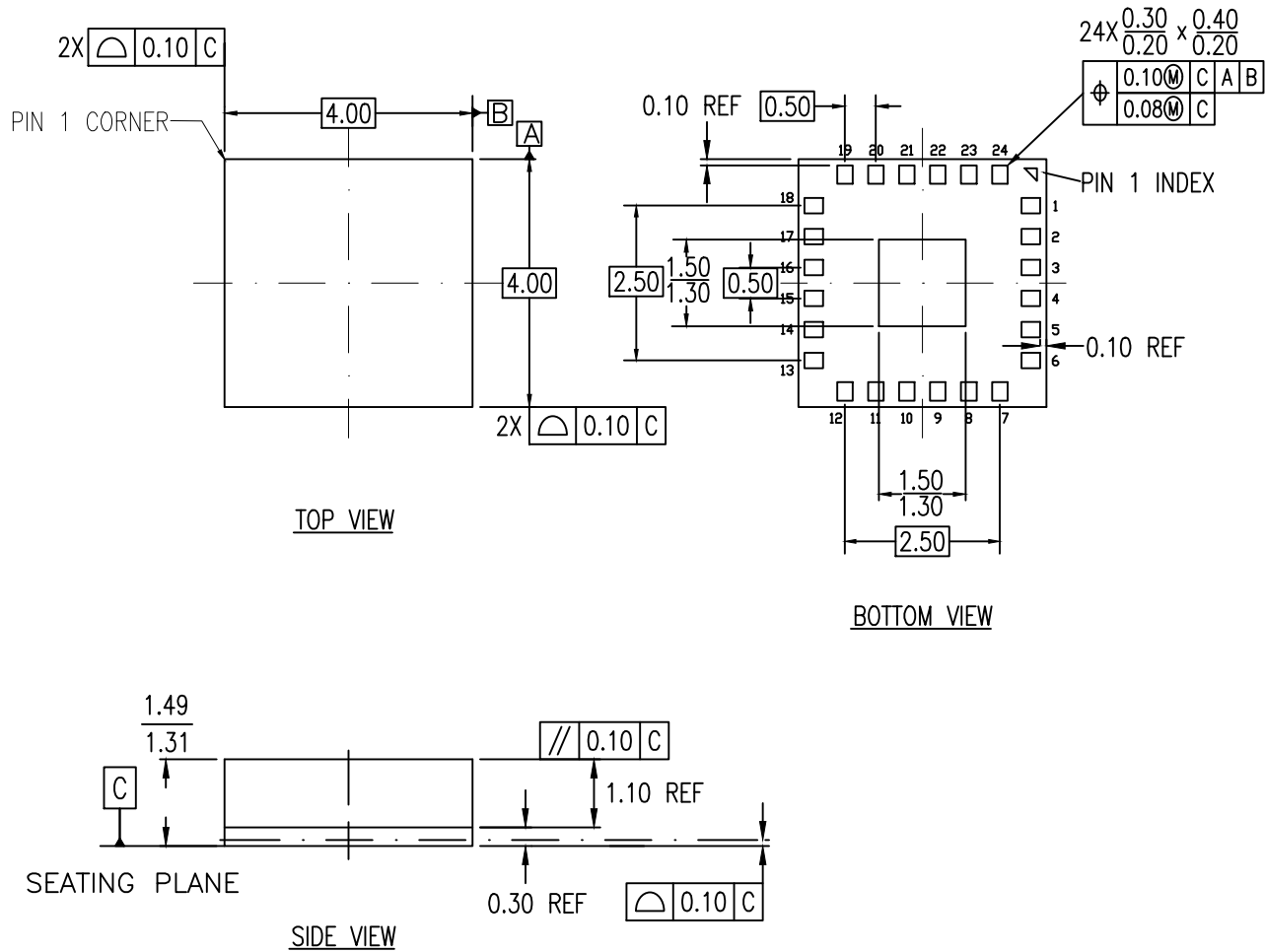
SIDE VIEW

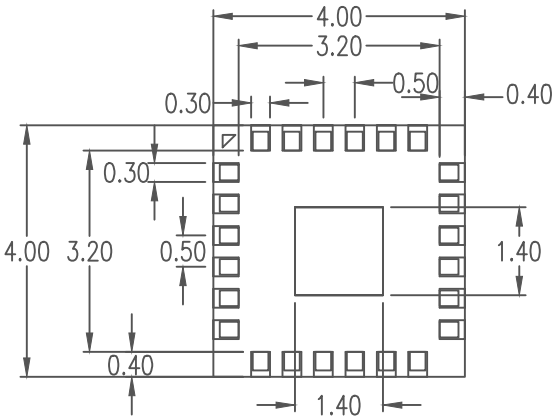


RECOMMENDED LAND PATTERN  
(PCB Top View, NSMD Design)

## NOTES:

1. JEDEC compatible.
2. All dimensions are in mm and angles are in degrees.
3. Use  $\pm 0.05$  mm for the non-toleranced dimensions.
4. Numbers in ( ) are for references only.





RECOMMENDED LAND PATTERN DIMENSION

- NOTES:
- 1. ALL DIMENSION ARE IN mm. ANGLES IN DEGREES.
  - 2. TOP DOWN VIEW. AS VIEWED ON PCB.
  - 3. LAND PATTERN RECOMMENDATION PER IPC-7351B GENERIC REQUIREMENT FOR SURFACE MOUNT DESIGN AND LAND PATTERN.

| Package Revision History |         |                 |
|--------------------------|---------|-----------------|
| Date Created             | Rev No. | Description     |
|                          |         |                 |
| Sept 15, 2017            | Rev 00  | Initial Release |

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